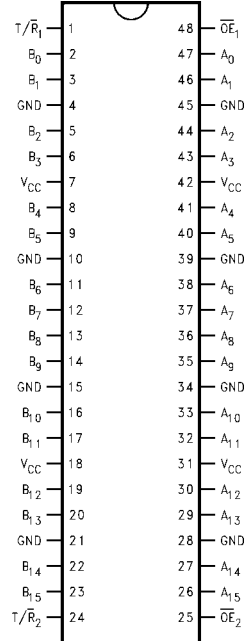
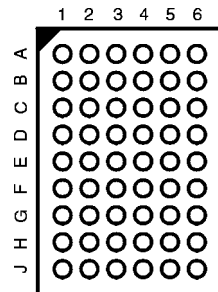


## Connection Diagrams

Pin Assignment for SSOP and TSSOP



Pin Assignment for FBGA



(Top Thru View)

## Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
$T/\overline{R}_n$	Transmit/Receive Input
$A_0-A_{15}$	Side A Inputs/3-STATE Outputs
$B_0-B_{15}$	Side B Inputs/3-STATE Outputs
NC	No Connect

## FBGA Pin Assignments

	1	2	3	4	5	6
<b>A</b>	$B_0$	NC	$T/\overline{R}_1$	$\overline{OE}_1$	NC	$A_0$
<b>B</b>	$B_2$	$B_1$	NC	NC	$A_1$	$A_2$
<b>C</b>	$B_4$	$B_3$	$V_{CC}$	$V_{CC}$	$A_3$	$A_4$
<b>D</b>	$B_6$	$B_5$	GND	GND	$A_5$	$A_6$
<b>E</b>	$B_8$	$B_7$	GND	GND	$A_7$	$A_8$
<b>F</b>	$B_{10}$	$B_9$	GND	GND	$A_9$	$A_{10}$
<b>G</b>	$B_{12}$	$B_{11}$	$V_{CC}$	$V_{CC}$	$A_{11}$	$A_{12}$
<b>H</b>	$B_{14}$	$B_{13}$	NC	NC	$A_{13}$	$A_{14}$
<b>J</b>	$B_{15}$	NC	$T/\overline{R}_2$	$\overline{OE}_2$	NC	$A_{15}$

## Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus $B_0-B_7$ Data to Bus $A_0-A_7$
L	H	Bus $A_0-A_7$ Data to Bus $B_0-B_7$
H	X	HIGH-Z State on $A_0-A_7, B_0-B_7$

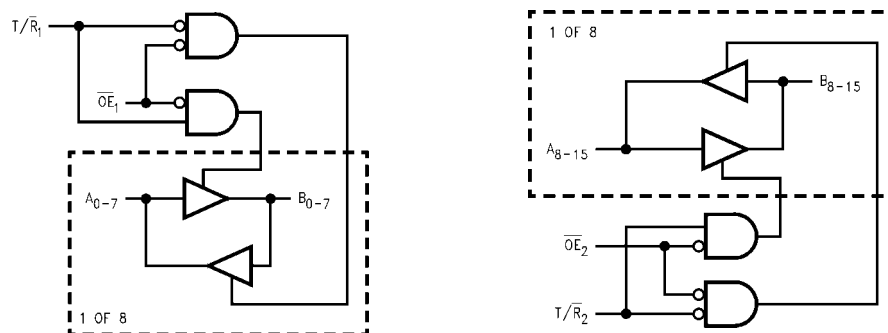
Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus $B_8-B_{15}$ Data to Bus $A_8-A_{15}$
L	H	Bus $A_8-A_{15}$ Data to Bus $B_8-B_{15}$
H	X	HIGH-Z State on $A_8-A_{15}, B_8-B_{15}$

H = HIGH Voltage Level  
 L = LOW Voltage Level  
 X = Immaterial  
 Z = High Impedance

## Functional Description

The LVT16245 and LVTH16245 contain sixteen non-inverting bidirectional buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

## Logic Diagrams



**Note:** Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

**Absolute Maximum Ratings**(Note 3)

Symbol	Parameter	Value	Conditions	Units
$V_{CC}$	Supply Voltage	-0.5 to +4.6		V
$V_I$	DC Input Voltage	-0.5 to +7.0		V
$V_O$	Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		-0.5 to +7.0	Output in HIGH or LOW State (Note 4)	
$I_{IK}$	DC Input Diode Current	-50	$V_I < GND$	mA
$I_{OK}$	DC Output Diode Current	-50	$V_O < GND$	mA
$I_O$	DC Output Current	64	Output at HIGH State, $V_O > V_{CC}$	mA
		128	Output at LOW State, $V_O > V_{CC}$	
$I_{CC}$	DC Supply Current per Supply Pin	±64		mA
$I_{GND}$	DC Ground Current per Ground Pin	±128		mA
$T_{STG}$	Storage Temperature Range	-65 to +150		°C

**Recommended Operating Conditions**

Symbol	Parameter	Min	Max	Units
$V_{CC}$	Supply Voltage	2.7	3.6	V
$V_I$	Input Voltage	0	5.5	V
$I_{OH}$	HIGH-Level Output Current		-32	mA
$I_{OL}$	LOW-Level Output Current		64	mA
$T_A$	Free-Air Operating Temperature	-40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, $V_{IN} = 0.8V-2.0V$ , $V_{CC} = 3.0V$	0	10	ns/V

**Note 3:** Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

**Note 4:**  $I_O$  Absolute Maximum Ratings must be observed.

**DC Electrical Characteristics**

Symbol	Parameter	$V_{CC}$ (V)	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		Units	Conditions
			Min	Max		
$V_{IK}$	Input Clamp Diode Voltage	2.7		-1.2	V	$I_I = -18\text{ mA}$
$V_{IH}$	Input HIGH Voltage	2.7-3.6	2.0		V	$V_O \leq 0.1V$ or
$V_{IL}$	Input LOW Voltage	2.7-3.6		0.8	V	$V_O \geq V_{CC} - 0.1V$
$V_{OH}$	Output HIGH Voltage	2.7-3.6	$V_{CC} - 0.2$		V	$I_{OH} = -100\text{ }\mu\text{A}$
		2.7	2.4			$I_{OH} = -8\text{ mA}$
		3.0	2.0			$I_{OH} = -32\text{ mA}$
$V_{OL}$	Output LOW Voltage	2.7		0.2	V	$I_{OL} = 100\text{ }\mu\text{A}$
		2.7		0.5		$I_{OL} = 24\text{ mA}$
		3.0		0.4		$I_{OL} = 16\text{ mA}$
		3.0		0.5		$I_{OL} = 32\text{ mA}$
		3.0		0.55		$I_{OL} = 64\text{ mA}$
$I_{I(HOLD)}$ (Note 5)	Bushold Input Minimum Drive	3.0	75		$\mu\text{A}$	$V_I = 0.8V$
			-75			$V_I = 2.0V$
$I_{I(OD)}$ (Note 5)	Bushold Input Over-Drive Current to Change State	3.0	500		$\mu\text{A}$	(Note 6)
			-500			(Note 7)
$I_I$	Input Current	3.6		10	$\mu\text{A}$	$V_I = 5.5V$
		Control Pins	3.6	±1		$V_I = 0V$ or $V_{CC}$
		Data Pins	3.6	-5		$V_I = 0V$
				1		$V_I = V_{CC}$
$I_{OFF}$	Power Off Leakage Current	0		±100	$\mu\text{A}$	$0V \leq V_I$ or $V_O \leq 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Output Current	0-1.5		±100	$\mu\text{A}$	$V_O = 0.5V$ to $3.0V$ $V_I = GND$ or $V_{CC}$
$I_{OZL}$	3-STATE Output Leakage Current	3.6		-5	$\mu\text{A}$	$V_O = 0.5V$
$I_{OZL}$ (Note 5)	3-STATE Output Leakage Current	3.6		-5	$\mu\text{A}$	$V_O = 0.0V$

**DC Electrical Characteristics** (Continued)

Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = -40°C to +85°C		Units	Conditions
			Min	Max		
I <sub>OZH</sub>	3-STATE Output Leakage Current	3.6		5	μA	V <sub>O</sub> = 3.0V
I <sub>OZH</sub> (Note 5)	3-STATE Output Leakage Current	3.6		5	μA	V <sub>O</sub> = 3.6V
I <sub>OZH</sub> <sup>+</sup>	3-STATE Output Leakage Current	3.6		10	μA	V <sub>CC</sub> < V <sub>O</sub> ≤ 5.5V
I <sub>CCH</sub>	Power Supply Current	3.6		0.19	mA	Outputs HIGH
I <sub>CCL</sub>	Power Supply Current	3.6		5.0	mA	Outputs LOW
I <sub>CCZ</sub>	Power Supply Current	3.6		0.19	mA	Outputs Disabled
I <sub>CCZ</sub> <sup>+</sup>	Power Supply Current	3.6		0.19	mA	V <sub>CC</sub> ≤ V <sub>O</sub> ≤ 5.5V, Outputs Disabled
ΔI <sub>CC</sub> (Note 8)	Increase in Power Supply Current	3.6		0.2	mA	One Input at V <sub>CC</sub> - 0.6V Other Inputs at V <sub>CC</sub> or GND

**Note 5:** Applies to bushold versions only (74LVTH16245).

**Note 6:** An external driver must source at least the specified current to switch from LOW-to-HIGH.

**Note 7:** An external driver must sink at least the specified current to switch from HIGH-to-LOW.

**Note 8:** This is the increase in supply current for each input that is at the specified voltage level rather than V<sub>CC</sub> or GND.

**Dynamic Switching Characteristics** (Note 9)

Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			Units	Conditions C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500Ω
			Min	Typ	Max		
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3		0.8		V	(Note 10)
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3		-0.8		V	(Note 10)

**Note 9:** Characterized in SSOP package. Guaranteed parameter, but not tested.

**Note 10:** Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. Output under test held LOW.

**AC Electrical Characteristics**

Symbol	Parameter	T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500Ω				Units
		V <sub>CC</sub> = 3.3V ± 0.3V		V <sub>CC</sub> = 2.7V		
		Min	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay Data to Output	1.5	3.5	1.5	3.9	ns
t <sub>PHL</sub>		1.3	3.5	1.3	3.9	
t <sub>PZH</sub>	Output Enable Time	1.5	4.5	1.5	5.3	ns
t <sub>PZL</sub>		1.6	5.3	1.6	6.9	
t <sub>PHZ</sub>	Output Disable Time	2.3	5.4	2.3	6.1	ns
t <sub>PLZ</sub>		2.2	5.1	2.2	5.4	
t <sub>OSHL</sub>	Output to Output Skew					ns
t <sub>OSLH</sub>	(Note 11)		1.0		1.0	

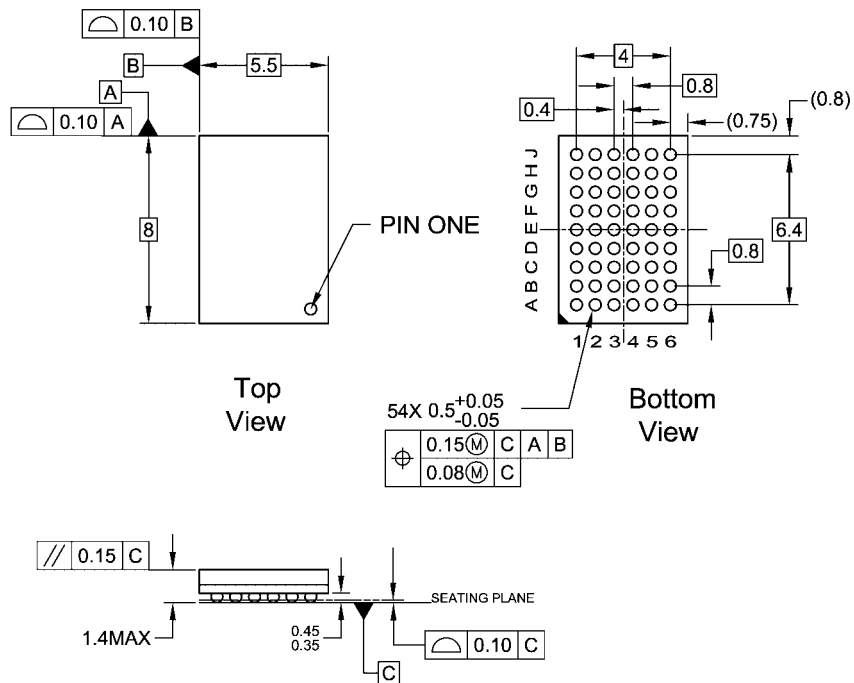
**Note 11:** Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSH</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>). Parameter guaranteed by design.

**Capacitance** (Note 12)

Symbol	Parameter	Conditions	Typical	Units
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 0V, V <sub>I</sub> = 0V or V <sub>CC</sub>	4	pF
C <sub>IO</sub>	Input/Output Capacitance	V <sub>CC</sub> = 3.0V, V <sub>O</sub> = 0V or V <sub>CC</sub>	8	pF

**Note 12:** Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

# Physical Dimensions inches (millimeters) unless otherwise noted



## NOTES:

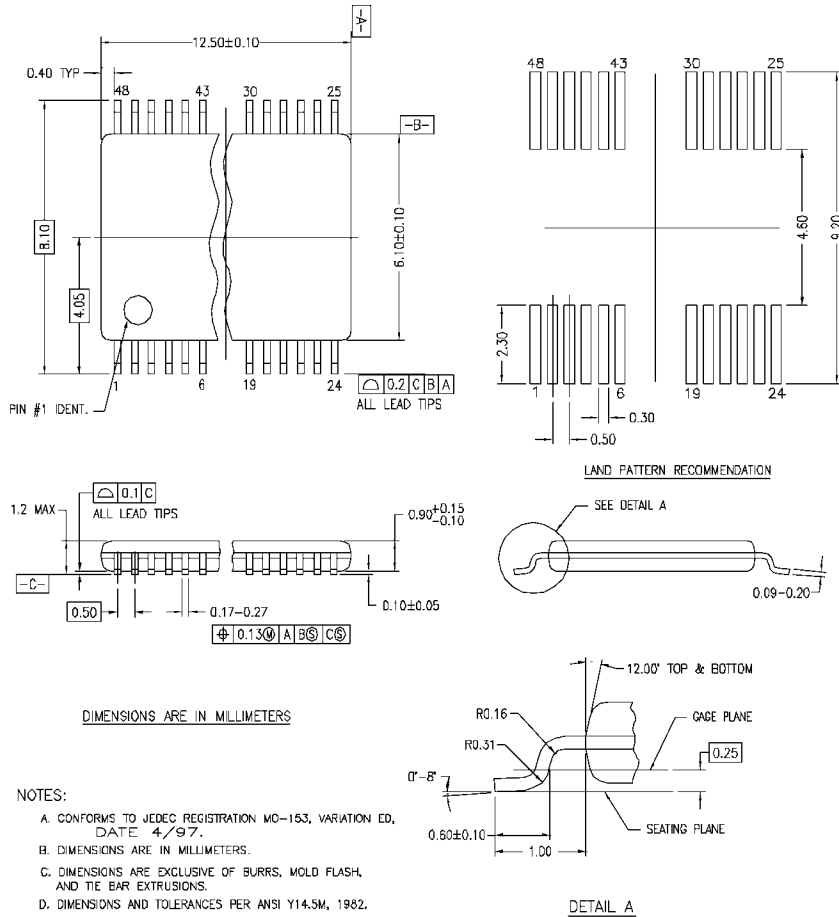
- A. THIS PACKAGE CONFORMS TO JEDEC M0-205
- B. ALL DIMENSIONS IN MILLIMETERS
- C. LAND PATTERN RECOMMENDATION: NSMD (Non Solder Mask Defined)
- D. DRAWING CONFORMS TO ASME Y14.5M-1994

BGA54ArevD

**54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide**  
**Package Number BGA54A**  
**Preliminary**



## Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



MTD48REV C

### 48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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